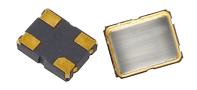




Low Voltage Crystal Oscillator AEC-Q200 Qualified

0.9V ~ 1.5V CMOS XO

LXQ Series



Product Features

- Low V_{DD} Range: 0.9V ~ 1.5V
 Frequency Range: 20 ~ 54MHz
 Low Phase Jitter: <1ps RMS max.
- Low I_{DD}: <4mA
- AEC-Q200 compliant Grade 1
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The LXQ CMOS XO series are suitable for automotive applications requiring specific change control; these parts are AEC-Q200 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

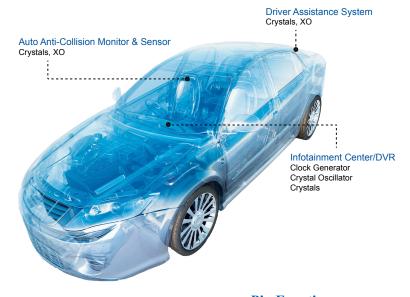
https://www.diodes.com/quality/product-definitions/

Product Description

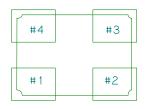
The DIODES™ LXQ XO series are high performance CMOS crystal oscillator families with very low jitter performance. They support 0.9V/1.0V/1.2V/1.5V voltages and consume very low operating current. They are designed to meet the clock source specifications for automotive applications with low voltage power rail.

Applications

• Automotive Equipments



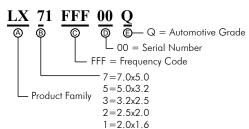
Top View Pin Location



Pin Functions:

Pin	Function				
1	OE Function				
2	Ground				
3	Output				
4	VDD				

Part Ordering Information:



Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

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Electrical Performance

Parameter		Min.	Тур.	Max.	Units	Notes
Output Frequency		20		54	MHz	
Supply Voltage		1.425	1.5	1.575		
		1.14	1.2	1.26	V	
		0.95	1.0	1.05		
		0.855	0.9	0.945		
Supply Current, Output Enabled				4	mA	
Supply Current, Output Disabled only				100	uA	
Frequency Stability		±20		±50	ppm	
Operating Temperature Range		-40		+125	°C	
Output Logic 0, V _{OL}				0.2 V _{DD}	V	
Output Logic 1, V _{OH}		0.8 V _{DD}			V	
Output Load				15	pF	
Duty Cycle	Duty Cycle			55	%	Measured 50% V _{DD}
Rise and Fall Time				4	ns	Measured 20/80% of waveform
Jitter, Accumulated, RMS (1-σ)				6	ps	20.000 adjacent periods
Jitter, Phase RMS, at 0.9~1.0V	< 40MHz			2		12kHz to 5 MHz frequency band
	>=40MHz			2	***	12kHz to 20 MHz frequency band
Jitter, Phase RMS, at 1.2~1.5V	< 40MHz			1	ps	12kHz to 5 MHz frequency band
	>=40MHz			1		12kHz to 20 MHz frequency band
Jitter, pk-pk				50	ps	100,000 random periods

Notes:

Output Enable / Disable Function

Parameter	Min.	Тур.	Max.	Units	Notes
Input Voltage (pin 1), Output Enable	0.7 V _{DD}			V	or open
Input Voltage (pin 1), Output Disable (low power standby)			0.3 V _{DD}	V	Output is Hi-Z
Output Disable Delay			50	us	
Output Enable Delay			2	ms	
Start up Time			10	ms	

Absolute Maximum Ratings

Parameter	Min.	Тур.	Max.	Units	Notes
Storage Temperature	-55		+125	°C	

Stability includes all combinations of operating temperature, load changes, rated input (supply) voltage changes, initial calibration tolerance (25°C), aging (1 year at 25°C average effective ambient temperature), shock and vibration.

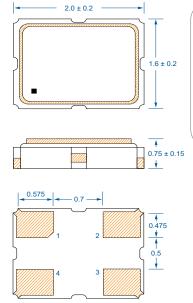
For specifications other than those listed, please contact sales.





Low Voltage Crystal Oscillator AEC-Q200 Qualified

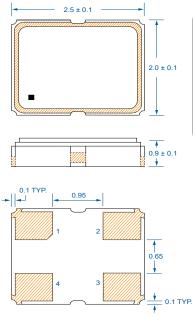
Package: 2.0x1.6 (Scale: none; dimensions are in mm)

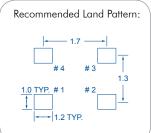


Recommended Land Pattern: - 1.4 --- 0.3 0.8

*Extended high frequency power decoupling is recommended (see test circuit for minimum recommendation). To ensure optimal performance, do not route RF traces beneath the package.

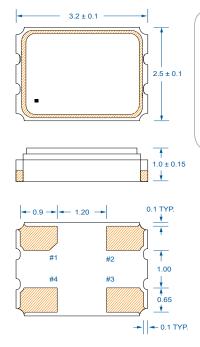
Package: 2.5x2.0 (Scale: none; dimensions are in mm)



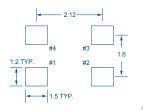


*Extended high frequency power decoupling is recommended (see test circuit for minimum recommendation). To ensure optimal performance, do not route RF traces beneath the package.

Package: 3.2x2.5 (Scale: none; dimensions are in mm)

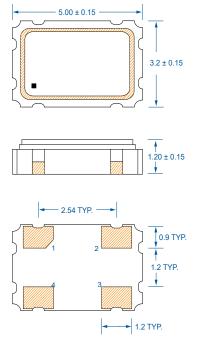


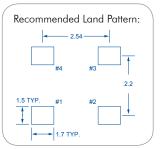
Recommended Land Pattern:



*Extended high frequency power decoupling is recommended (see test circuit for minimum recommendation). To ensure optimal performance, do not route RF traces beneath the package.

Package: 5.0x3.2 (Scale: none; dimensions are in mm)



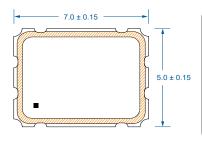


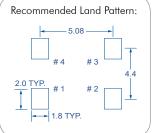
*Extended high frequency power decoupling is recommended (see test circuit for minimum recommendation). To ensure optimal performance, do not route RF traces beneath the package.



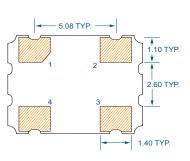
Low Voltage Crystal Oscillator AEC-Q200 Qualified

Package: 7.0x5.0 (Scale: none; dimensions are in mm)









*Extended high frequency power decoupling is recommended (see test circuit for minimum recommendation). To ensure optimal performance, do not route RF traces beneath the package.

For the latest product information visit: https://www.diodes.com/products/connectivity-and-timing/crystal-and-crystal-oscillator/crystaloscillator-cxo/

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